### **General Description**

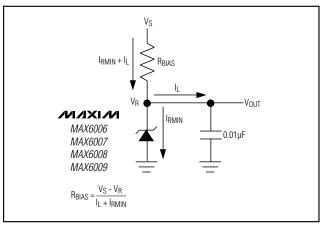
The MAX6006–MAX6009 ultra-low-power shunt references are ideal for space-critical and low-power applications. They are offered in 3-pin SOT23 packages, and the minimum operating current is guaranteed to be <1 $\mu$ A. The devices feature low temperature coefficients of <30ppm/°C and initial accuracy of better than 0.2%.

Available in +1.25V, +2.048V, +2.5V, and 3V output voltages, the MAX6006–MAX6009 have references of +1.25V, +2.048V, +2.5V, and +3.0V, respectively. The devices can be used as lower-power, higher-precision upgrades to the ICL8069, LM385, LT1004, and LM4040 references. The MAX6006–MAX6009 are available in two grades: A and B. The A grade features a temperature coefficient of 30ppm/°C over the extended temperature range of -40°C to +85°C, with an initial accuracy of 0.2%. Grade B features a temperature coefficient of 75ppm/°C with an initial accuracy of 0.5%. MAX6006 in+1.25V and MAX6008 in +2.5V are offered in 8-pin SOIC packages, as plug in upgrades for LT1004 and LM285.

#### **Applications**

Battery-Powered Equipment Portable Meters Precision Regulators A/D and D/A Converters

Ordering Information appears at end of data sheet



### **Typical Operating Circuit**

### 

*For free samples and the latest literature, visit www.maxim-ic.com or phone 1-800-998-8800. For small orders, phone 1-800-835-8769.* 

TOP VIEW

OUT

GND 2

SOT23-3

#### Features

- ♦ Ultra-Low Operating Current: Guaranteed <1µA</p>
- Small 3-Pin SOT23 Package
- Initial Voltage Accuracy: 0.2%
- Temperature Coefficient: 30ppm/°C max
- ♦ Temperature Range: -40°C to +85°C
- Factory-Trimmed Output Voltages: +1.25V, +2.048V, +2.5V, +3.0V
- ♦ Wide Operating Range: 1µA to 2mA

#### \_Selector Guide

PART	OUTPUT VOLTAGE (V)	INITIAL ACCURACY (%)	TEMPERATURE COEFFICIENT (ppm/°C)
MAX6006A	1.25	0.2	30
MAX6006B	1.25	0.5	75
MAX6007A	2.048	0.2	30
MAX6007B	2.048	0.5	75
MAX6008A	2.5	0.2	30
MAX6008B	2.5	0.5	75
MAX6009A	3.0	0.2	30
MAX6009B	3.0	0.5	75

N.C.

N.C.

N.C. 3

GND 4

3 I.C.

### \_Pin Configuration

SO

Maxim Integrated Products 1

MAX6006

MAX6007 MAX6008

MAX6009

8 OUT

7 N.C.

6 OUT

5 N.C.

#### **ABSOLUTE MAXIMUM RATINGS**

Operating Current (OUT to GND)	20mA
Forward Current (GND to OUT)	20mA
Continuous Power Dissipation ( $T_A = +70^{\circ}C$ )	
3-Pin SOT23 (derate 4mW/°C above +70°C)	320mW
8-Pin SO (derate 5.48mW/°C above +70°C)	471mW

Operating Temperature Range	40°C to +85°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### **ELECTRICAL CHARACTERISTICS—MAX6006**

PARAMETER	SYMBOL	со	NDITIONS	MIN	ТҮР	MAX	UNITS
Reverse Breakdown Voltage	VR	T <sub>A</sub> = +25°C,	MAX6006A (0.2%)	1.2475	1.2500	1.2525	- V
	٧K	I <sub>R</sub> = 1.2μΑ	MAX6006B (0.5%)	1.2438	1.2500	1.2563	
Minimum Operating Current	I <sub>RMIN</sub>	V <sub>R</sub> change <0.2% f	rom V <sub>R</sub> at $I_R = 1.2\mu A$		0.5	1.0	μΑ
Reverse Breakdown Change		$I_{\rm R} = 1.2 \mu A$ to 200 $\mu A$	R = 1.2μA to 200μA			1.0	mV
with Current		$I_{R} = 200\mu A$ to 2mA				2.0	
Reverse Dynamic Impedance		$I_R = 1.2\mu A$ to 2mA (Note 2)				1.5	Ω
Low-Frequency Noise		I <sub>R</sub> = 1.2µA, f = 0.1⊦	$I_{\rm R}$ = 1.2µA, f = 0.1Hz to 10Hz		30		μV <sub>p-p</sub>
Temperature Coefficient	тс		MAX6006A			30	nnm/0C
(Note 3)	ĨĊ	Ι <sub>R</sub> = 1.2μΑ	MAX6006B			75	ppm/°C
Long-Term Drift		1000h at $T_A = +25^{\circ}C$			150		ppm
Thermal Hysteresis (Note 4)					200		ppm

(T<sub>A</sub> = -40°C to +85°C, unless otherwise noted. Typical values are at T<sub>A</sub> = +25°C.) (Note 1)

#### ELECTRICAL CHARACTERISTICS—MAX6007

 $(T_A = -40^{\circ}C \text{ to } +85^{\circ}C, \text{ unless otherwise noted. Typical values are at } T_A = +25^{\circ}C.)$  (Note 1)

PARAMETER	SYMBOL	CONDITIONS		MIN	ТҮР	МАХ	UNITS
Deverse Breekdewn Veltage		T <sub>A</sub> = +25°C,	MAX6007A (0.2%)	2.0439	2.048	2.0521	V
Reverse Breakdown Voltage	VR	$I_R = 1.2 \mu A$	MAX6007B (0.5%)	2.0378	2.048	2.0582	v
Minimum Operating Current	IRMIN	V <sub>R</sub> change <0.2% fr	om V <sub>R</sub> at I <sub>R</sub> = 1.2µA		0.5	1.0	μA
Reverse Breakdown Change		I <sub>R</sub> = 1.2μA to 200μA				1.3	mV
with Current		$I_{\rm R} = 200\mu$ A to 2mA				2.3	
Reverse Dynamic Impedance		$I_R = 1.2\mu A$ to 2mA (Note 2)				1.8	Ω
Low-Frequency Noise		$I_R = 1.2\mu A$ , f = 0.1Hz to 10Hz			50		μV <sub>p-p</sub>
Temperature Coefficient	TC I <sub>R</sub> = 1.2µA		MAX6007A			30	nnm/0C
(Note 3)		$IR = 1.2\mu A$	MAX6007B			75	ppm/°C
Long-Term Drift		1000h at T <sub>A</sub> = +25°C			150		ppm
Thermal Hysteresis (Note 4)					200		ppm

#### **ELECTRICAL CHARACTERISTICS—MAX6008**

 $(T_A = -40^{\circ}C \text{ to } +85^{\circ}C, \text{ unless otherwise noted. Typical values are at } T_A = +25^{\circ}C.)$  (Note 1)

PARAMETER	SYMBOL	CONDITIONS		MIN	ТҮР	MAX	UNITS	
Reverse Breakdown Voltage	V	T <sub>A</sub> = +25∘C,	MAX6008A (0.2%)	2.4950	2.5000	2.5050	V	
neverse breakdown voltage	V <sub>R</sub>	I <sub>R</sub> = 1.2μA	MAX6008B (0.5%)	2.4875	2.5000	2.5125	Ň	
Minimum Operating Current	I <sub>RMIN</sub>	V <sub>R</sub> change <0.2% fro	om V <sub>R</sub> at I <sub>R</sub> = 1.2µA		0.5	1.0	μA	
Reverse Breakdown Change with		I <sub>R</sub> = 1.2μA to 200μA				1.5	mV	
Current		I <sub>R</sub> = 200μA to 2mA				2.5	1110	
Reverse Dynamic Impedance		I <sub>R</sub> = 1.2μA to 2mA (Note 2)				2	Ω	
Low-Frequency Noise		$I_{R} = 1.2 \mu A, f = 0.1 Hz$	z to 10Hz		60		μ <sup>V</sup> p-p	
Temperature Coefficient	TC	Ι <sub>B</sub> = 1.2μΑ	MAX6008A			30	ppm/₀C	
(Note 3)	10	$R = 1.2\mu$	MAX6008B			75	ppm/00	
Long-Term Drift		1000h at T <sub>A</sub> = +25°C			150		ppm	
Thermal Hysteresis (Note 4)					200		ppm	

MAX6006-MAX6009

#### **ELECTRICAL CHARACTERISTICS—MAX6009**

 $(T_A = -40^{\circ}C \text{ to } +85^{\circ}C, \text{ unless otherwise noted. Typical values are at } T_A = +25^{\circ}C.)$  (Note 1)

PARAMETER	SYMBOL	CONDITIONS		MIN	ТҮР	МАХ	UNITS
	\/_	T <sub>A</sub> = +25°C,	MAX6009A (0.2%)	2.9940	3.000	3.0060	- v
Reverse Breakdown Voltage	VR	$I_{R} = 1.2 \mu A$	MAX6009B (0.5%)	2.9850	3.000	3.0150	
Minimum Operating Current	IRMIN	V <sub>R</sub> change <0.2% f	from V <sub>R</sub> at I <sub>R</sub> = 1.2µA		0.5	1.0	μA
Reverse Breakdown Change		I <sub>R</sub> = 1.2μA to 200μA				1.7	m)/
with Current		I <sub>R</sub> = 200μA to 2mA				2.7	mV
Reverse Dynamic Impedance		$I_R = 1.2\mu A$ to 2mA (Note 2)				2.2	Ω
Low-Frequency Noise		$I_{R} = 1.2 \mu A$ , f = 0.1Hz to 10Hz			75		μV <sub>p-p</sub>
Temperature Coefficient	ТС	I= 1.00A	MAX6009A			30	
(Note 3)	IC	I <sub>R</sub> = 1.2μΑ	MAX6009B			75	ppm/°C
Long-Term Drift		1000h at T <sub>A</sub> = +25°C			150		ppm
Thermal Hysteresis (Note 4)					200		ppm

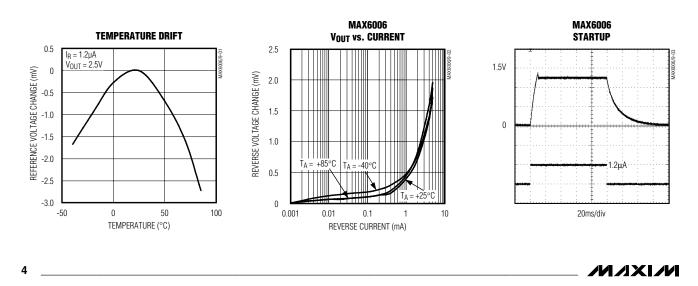
**Note 1:** All devices are 100% production tested at  $T_A = +25^{\circ}C$  and are guaranteed by design for  $T_A = T_{MIN}$  to  $T_{MAX}$ , as specified. **Note 2:** This parameter is guaranteed by the "reverse breakdown change with current" test.

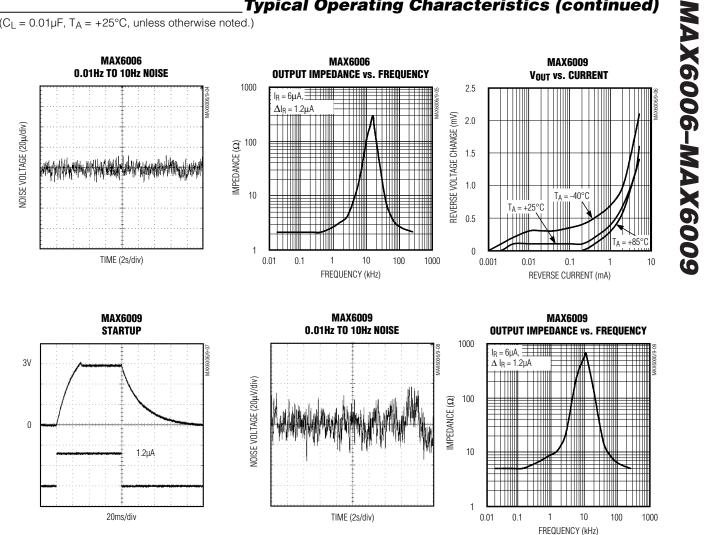
Note 3: TC is measured by the "box" method; i.e., (V<sub>MAX</sub> - V<sub>MIN</sub>) / (T<sub>MAX</sub> - T<sub>MIN</sub>).

Note 4: Thermal hysteresis is defined as the change in the +25°C output voltage after cycling the device from T<sub>MIN</sub> to T<sub>MAX</sub> .

### **Typical Operating Characteristics**

(C<sub>L</sub> =  $0.01\mu$ F, T<sub>A</sub> = +25°C, unless otherwise noted.)





### **Typical Operating Characteristics (continued)**

**1µA SOT23 Precision Shunt** 

**Voltage Reference** 

(C<sub>L</sub> = 0.01 $\mu$ F, T<sub>A</sub> = +25°C, unless otherwise noted.)



#### **Pin Description**

PIN NAME			FUNCTION				
SOT23	SO		Output Voltage. Bias OUT with a pullup resistor to a potential greater than OUT. Bypass OUT				
1	6, 8	OUT	to GND with a 0.01 $\mu$ F or larger capacitor.				
2	4	GND	Ground				
3	_	IC	Internally connected test point. Leave this pin unconnected, or connect to GND.				
— 1, 2, 3, 5, N.C. 7		N.C.	No connection. Not internally connected.				

#### **Detailed Description**

The MAX6006–MAX6009 are precision, two-terminal, series bandgap voltage references. On-chip thin-film resistors are laser trimmed to provide 0.2% output voltage accuracies. Voltages of +1.25V, +2.048V,+2.5V, and +3.0V are available in the space-saving SOT23 package (2.1mm × 2.7mm).

### **Applications Information**

#### **Output/Load Capacitance**

For devices in this family, OUT needs to be bypassed to GND with a 0.01µF or larger capacitor. In applications where the load or the supply can experience step changes, additional capacitance will reduce the amount of overshoot (or undershoot) and assist the circuit's transient response.

#### **Output Voltage Hysteresis**

Output voltage hysteresis is the change in the output voltage at  $T_A = +25^{\circ}C$  before and after the device is cycled over its entire operating temperature range. Hysteresis is caused by differential package stress appearing across the bandgap core transistors. The temperature hysteresis value is typically less than 200ppm.

#### Turn-On Time

The output capacitance and bias current of the MAX6006–MAX6009 greatly affects turn-on settling time. In the *Typical Operating Characteristics*, turn-on time is shown with a 10nF output capacitor and a 1.2µA bias current. Under these conditions, the MAX6006–MAX6009 settle in 40ms. Settling time will linearly decrease in proportion to the circuit's bias current.

### **Typical Applications**

In the typical shunt regulator application shown in Figure 1,  $R_{BIAS}\,$  is used to set the current through the load (I\_) and the current through the shunt regulator (I\_RMIN). There are two worst-case situations that  $R_{BIAS}\,$  needs to be sized for:

- R<sub>BIAS</sub> must be small enough that when V<sub>S</sub> (supply voltage) is at its minimum and I<sub>L</sub> is at its maximum, I<sub>RMIN</sub> is equal to at least the minimum operating current of the shunt regulator.
- 2)  $R_{BIAS}$  must be large enough that when  $V_S$  is at its maximum and IL is at its minimum, I\_{RMIN} is <2mA.

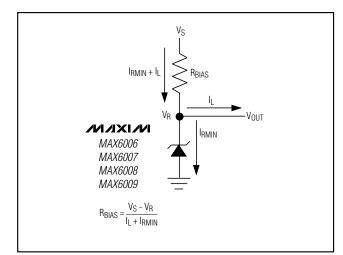
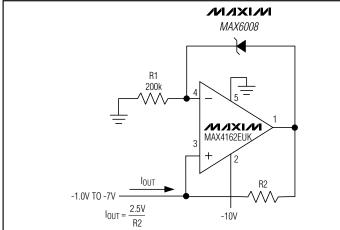
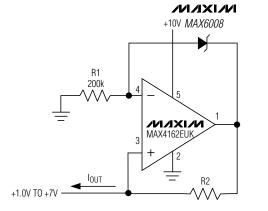


Figure 1. Typical Application Circuit





MAX6006-MAX6009

Figure 2. Precision 1µA to 1mA Current Sources

### **Ordering Information**

PART	TEMP. RANGE	PIN- PACKAGE	TOP MARK
MAX6006AEUR-T	-40°C to +85°C	3 SOT23	FZGH
MAX6006AESA	-40°C to +85°C	8 SO	
MAX6006BEUR-T	-40°C to +85°C	3 SOT23	FZGI
MAX6006BESA	-40°C to +85°C	8 SO	—
MAX6007AEUR-T	-40°C to +85°C	3 SOT23	FZGK
MAX6007BEUR-T	-40°C to +85°C	3 SOT23	FZGL
MAX6008AEUR-T	-40°C to +85°C	3 SOT23	FZGN
MAX6008AESA	-40°C to +85°C	8 SO	_
MAX6008BEUR-T	-40°C to +85°C	3 SOT23	FZGO
MAX6008BESA	-40°C to +85°C	8 SO	_
MAX6009AEUR-T	-40°C to +85°C	3 SOT23	FZGQ
MAX6009BEUR-T	-40°C to +85°C	3 SOT23	FZGR

#### \_Chip Information

TRANSISTOR COUNT: 60 PROCESS: BiCMOS

#### 

#### **Package Information** SOTPO3L.EPS NDTES: 1. D&E DO NOT INCLUDE MOLD FLASH. INCHES MILLIMETERS 2. MOLD FLASH OR PROTRUSIONS NOT TO DIM MAX MIN MAX MIN EXCEED .15mm (.006") А 0.031 0.047 0.787 1.194 3. CONTROLLING DIMENSION: MILLIMETER 0.025 Α1 0.001 0.005 0.127 В В 0.014 0.022 0.356 0.559 С 0.0034 0.006 0.086 0.152 D 0.105 0.120 2.667 3.048 Ε 0.047 0.055 1.194 1.397 0.070 0.080 е 1.778 2.032 -Н 0.082 0.098 2.083 2.489 0.305 0.004 0.012 0.102 S 0.017 0.022 0.432 0.559 0° 8° 0° 8° α 2 А //|/|X|//| PACKAGE DUTLINE, SDT-23, P Α1 1 21-0051 С

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